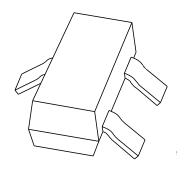
#### DISCRETE SEMICONDUCTORS

# DATA SHEET



# BB804 VHF variable capacitance double diode

Product specification Supersedes data of November 1993 File under Discrete Semiconductors, SC01 1996 May 03





### VHF variable capacitance double diode

#### **BB804**

#### **FEATURES**

- · Selected capacitance ranges
- Small plastic SMD package
- C8: 26 pF; ratio: 1.7
- Low series resistance.

#### **APPLICATIONS**

Electronic tuning in FM radio applications.

#### **DESCRIPTION**

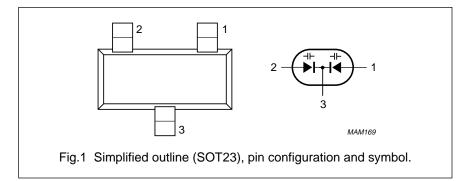
The BB804 is a variable capacitance double diode with a common cathode, fabricated in planar technology, and encapsulated in the SOT23 small plastic SMD package.

#### **MARKING**

TYPE NUMBER	CODE
BB804 R	SF 0
BB804 Y	SF 1
BB804 W	SF 2
BB804 G	SF 3

#### **PINNING**

PIN	DESCRIPTION
1	anode (a <sub>1</sub> )
2	anode (a <sub>2</sub> )
3	common cathode
	· · · · · · · · · · · · · · · · · · ·



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT		
Per diode						
V <sub>R</sub>	continuous reverse voltage	_	18	V		
I <sub>F</sub>	continuous forward current	_	50	mA		
T <sub>stg</sub>	storage temperature	-55	+150	°C		
Tj	operating junction temperature	<b>-55</b>	+125	°C		

Philips Semiconductors Product specification

# VHF variable capacitance double diode

**BB804** 

#### **ELECTRICAL CHARACTERISTICS**

 $T_j$  = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Per diode	Per diode						
I <sub>R</sub>	reverse current	V <sub>R</sub> = 16 V; see Fig.3	_	_	20	nA	
		V <sub>R</sub> = 16 V; T <sub>j</sub> = 60 °C; see Fig.3	_	_	200	nA	
r <sub>s</sub>	diode series resistance	f = 100 MHz; note 1	_	0.2	_	Ω	
C <sub>d</sub>	diode capacitance	$V_R = 2 \text{ V}$ ; f = 1 MHz; red 0; see Figs 2 and 4	42	_	43.5	pF	
		$V_R = 2 V$ ; f = 1 MHz; yellow 1; see Figs 2 and 4	43	_	44.5	pF	
		V <sub>R</sub> = 2 V; f = 1 MHz; white 2; see Figs 2 and 4	44	_	45.5	pF	
		$V_R = 2 \text{ V}$ ; f = 1 MHz; green 3; see Figs 2 and 4	45	_	46.5	pF	
C <sub>d (2V)</sub>	capacitance ratio	f = 1 MHz	1.65	_	1.75		
$\overline{C_{d(8V)}}$							

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#### Note

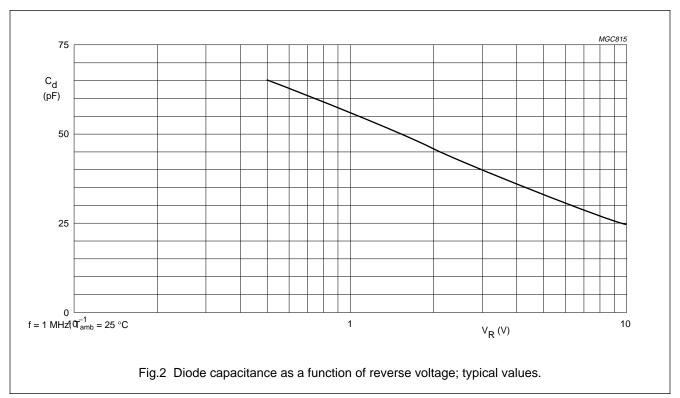
1.  $V_R$  is the value at which  $C_d$  = 38 pF.

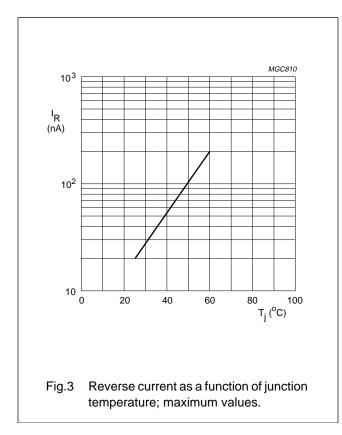
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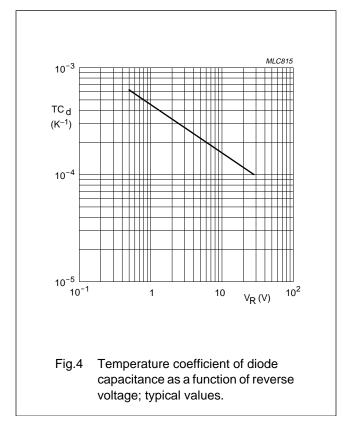
## VHF variable capacitance double diode

**BB804** 

#### **GRAPHICAL DATA**





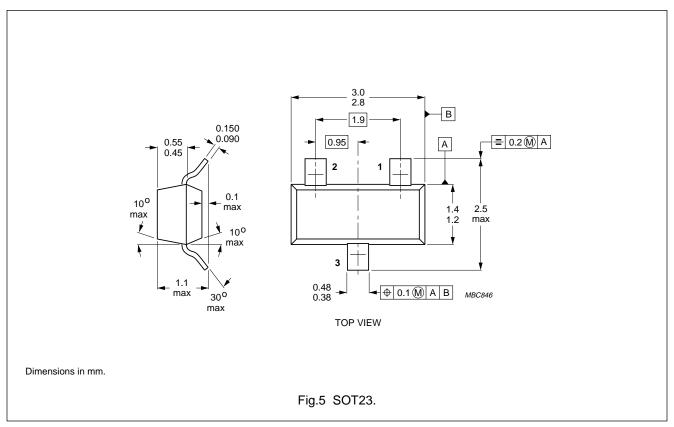


Philips Semiconductors Product specification

#### VHF variable capacitance double diode

**BB804** 

#### **PACKAGE OUTLINE**



#### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

#### **Limiting values**

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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